

**TEM-F-785 /1~40mW (TEM<sub>00</sub>)**

## INFRARED DIODE LASER AT 785nm

Infrared diode laser module at 785nm is made features of TEM<sub>00</sub> mode, ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



### SPECIFICATIONS

Wavelength (nm)	785±5	
Output power (mW)	>1,2,3.....40	
Transverse mode	TEM <sub>00</sub>	
Operating mode	CW	
Ellipticity	>0.98	
Beam quality (M <sup>2</sup> )	<1.1	
Power stability (rms, over 4 hours)	<1%, <3%, <5%	
Pointing stability after warm-up (mrad)	<0.05	
Polarization ratio	no fixed polarization	>50:1 (>100:1 optional)
Warm-up time (minutes)	<5	
Beam divergence, full angle (mrad)	<1.0	
Beam diameter at the aperture (mm)	~1.0	
Beam height from base plate (mm)	25	
Operating temperature (°C)	10~35	
Power supply (90-264VAC)	PSU-III-LED	PSU-III-FDA
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off	
Expected lifetime (hours)	10000	
Warranty period	1 year	



TEM-F-785	PSU-III-LED	PSU-III-FDA
 <b>111(L)×58(W)×45(H) mm<sup>3</sup>, 0.74kg</b>	 <b>154 (L) ×155(W) ×95 (H) mm<sup>3</sup>, 1.5kg</b>	 <b>133 (L) ×130(W) ×65 (H) mm<sup>3</sup>, 1.2kg</b>
		